DATA SHEET

CEL

NPN SILICON RF TRANSISTOR

NE46234 / 2SC4703 JEITA Part No.

NPN EPITAXIAL SILICON RF TRANSISTOR FOR HIGH-FREQUENCY LOW DISTORTION AMPLIFIER 3-PIN POWER MINIMOLD

DESCRIPTION

The NE46234 / 2SC4703 is designed for low distortion, low noise RF amplifier operating with low supply voltage (V_{CE} = 5 V). This low distortion characteristic makes it suitable for CATV, tele-communication and other use. It employs surface mount type plastic package, power minimold (SOT-89).

FEATURES

- Low distortion, low voltage: IM_2 = 55 dBc TYP., IM_3 = 76 dBc TYP. @ V_{CE} = 5 V, I_C = 50 mA, V_O = 105 dBμV/75Ω
- Large P_{tot} : P_{tot} = 1.8 W (Mounted on double-sided copper-clad 16 $cm^2 \times 0.7$ mm (t) ceramic substrate)
- Small package : 3-pin power minimold package

★ ORDERING INFORMATION

Part Number	Quantity	Supplying Form
NE46234-AZ 2SC4703-AZ	25 pcs (Non reel)	• 12 mm wide embossed taping • Collector face the perforation side of the tape
NE46234-T1-AZ 2SC4703-T1-AZ	1 kpcs/reel	

Remark To order evaluation samples, contact your nearby sales office.
The unit sample quantity is 25 pcs.

ABSOLUTE MAXIMUM RATINGS (T_A = +25°C)

Parameter	Symbol	Ratings	Unit
Collector to Base Voltage	V_{CBO}	25	V
Collector to Emitter Voltage	V_{CEO}	12	V
Emitter to Base Voltage	V_{EBO}	2.5	V
Collector Current	I_C	150	mA
Total Power Dissipation	P_{tot} Note	1.8	W
Junction Temperature	T_j	150	°C
★ Storage Temperature	T_{stg}	−65 to +150	°C

Note Mounted on double-sided copper-clad 16 $cm^2 \times 0.7$ mm (t) ceramic substrate

Caution Observe precautions when handling because these devices are sensitive to electrostatic discharge.

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.

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The mark ★ shows major revised points.

ELECTRICAL CHARACTERISTICS (T_A = +25°C)

	Parameter	Symbol	Test Conditions		MIN.	TYP.	MAX.	Unit
	DC Characteristics							
	Collector Cut-off Current	I_{CBO}	V_{CB} = 20 V, I_E = 0 mA		–	–	1.5	μA
	Emitter Cut-off Current	I_{EBO}	V_{EB} = 2 V, I_C = 0 mA		–	–	1.5	μA
★	DC Current Gain	h_{FE} Note 1	V_{CE} = 5 V, I_C = 50 mA		50	–	250	–
	RF Characteristics							
★	Gain Bandwidth Product	f_T	V_{CE} = 5 V, I_C = 50 mA		–	6.0	–	GHz
	Insertion Power Gain (1)	$\lvert S_{21e} \rvert^2$	V_{CE} = 5 V, I_C = 50 mA, f = 1 GHz		6.5	8.3	–	dB
	Insertion Power Gain (2)	$\lvert S_{21e} \rvert^2$	V_{CE} = 10 V, I_C = 20 mA, f = 1 GHz		–	8.5	–	dB
	Noise Figure	NF	V_{CE} = 5 V, I_C = 50 mA, f = 1 GHz		–	2.3	3.5	dB
	Collector Capacitance	C_{ob} Note 2	V_{CB} = 5 V, I_E = 0 mA, f = 1 MHz		–	1.5	2.5	pF
★	2nd Order Intermoduration Distortion	IM_2	I_C = 50 mA, V_O = 105 dBμV/75 Ω, f = 190 – 90 MHz	V_{CE} = 5 V	–	55	–	dBc
				V_{CE} = 10 V		63	–	
★	3rd Order Intermoduration Distortion	IM_3	I_C = 50 mA, V_O = 105 dBμV/75 Ω, f = 2 × 190 – 200 MHz	V_{CE} = 5 V	–	76	–	dBc
				V_{CE} = 10 V	–	81	–	

Notes 1. Pulse measurement: PW ≤ 350 μs, Duty Cycle ≤ 2%

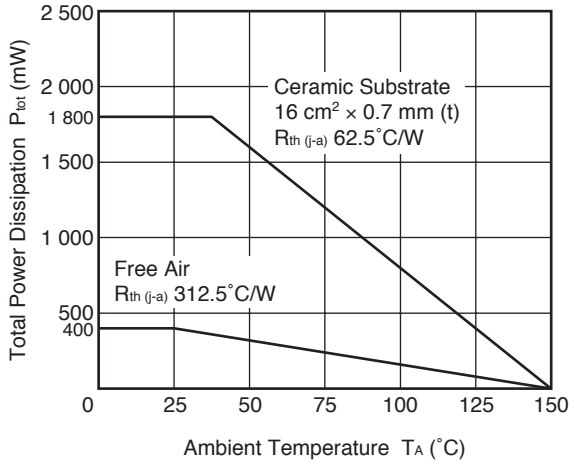
2. Collector to base capacitance when the emitter grounded

h_{FE} CLASSIFICATION

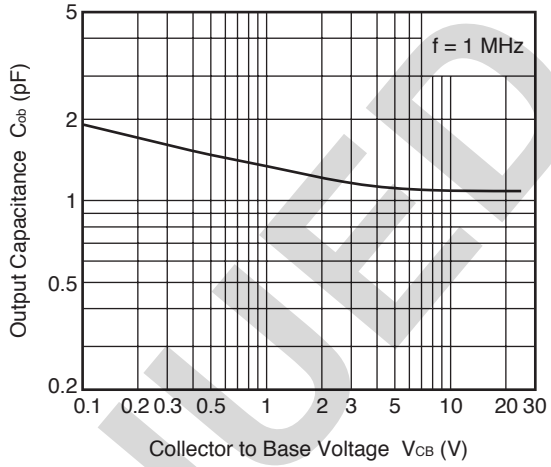
Rank	SH	SF	SE
Marking	SH	SF	SE
h_{FE} Value	50 to 100	80 to 160	125 to 250

★ TYPICAL CHARACTERISTICS (T_A = +25°C)

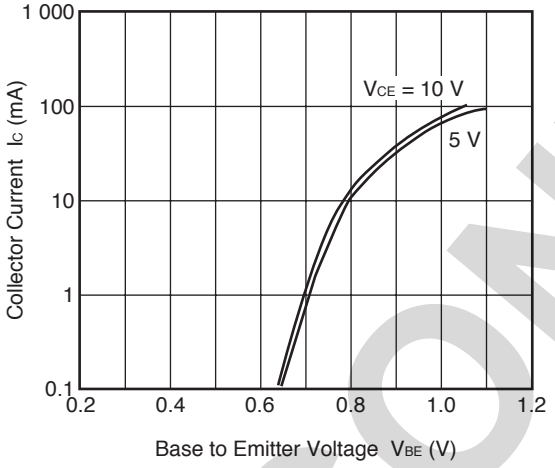
TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE



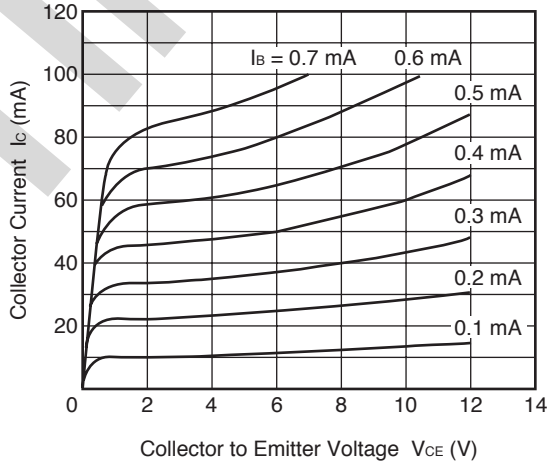
OUTPUT CAPACITANCE vs. COLLECTOR TO BASE VOLTAGE



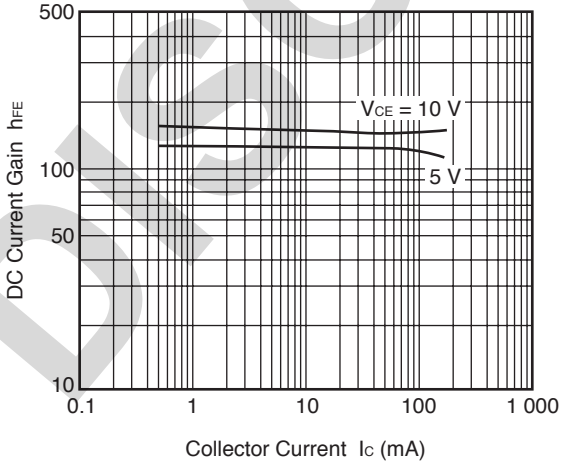
COLLECTOR CURRENT vs. BASE TO EMITTER VOLTAGE



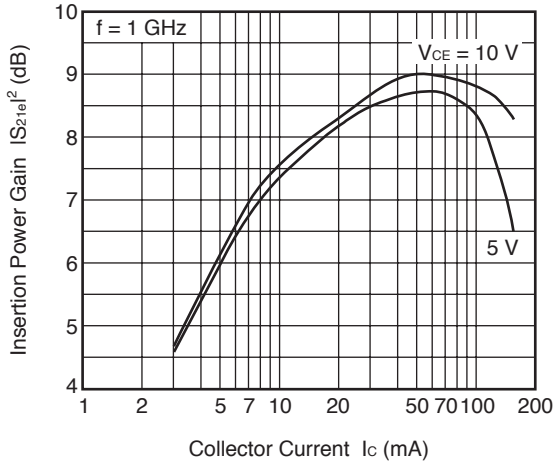
COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE



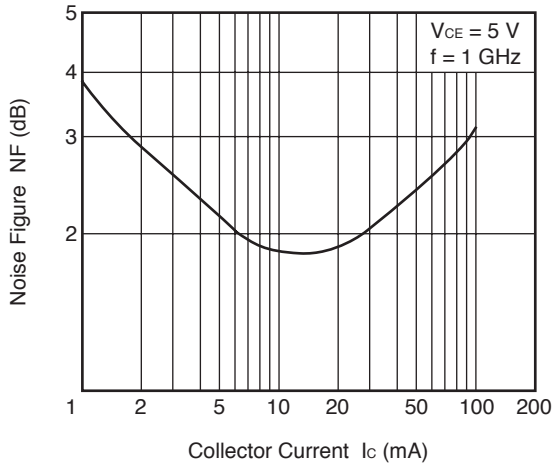
DC CURRENT GAIN vs. COLLECTOR CURRENT



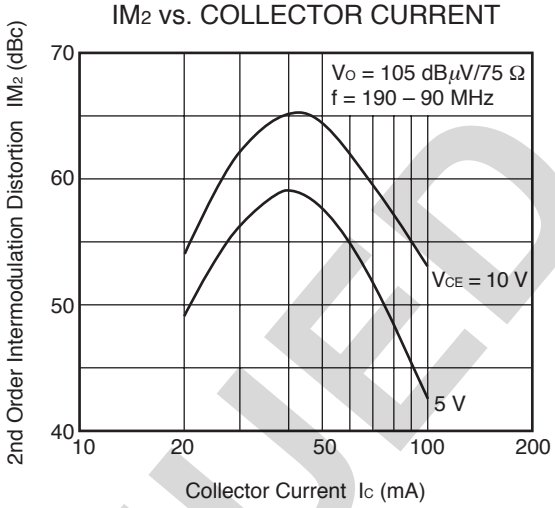
INSERTION POWER GAIN vs. COLLECTOR CURRENT



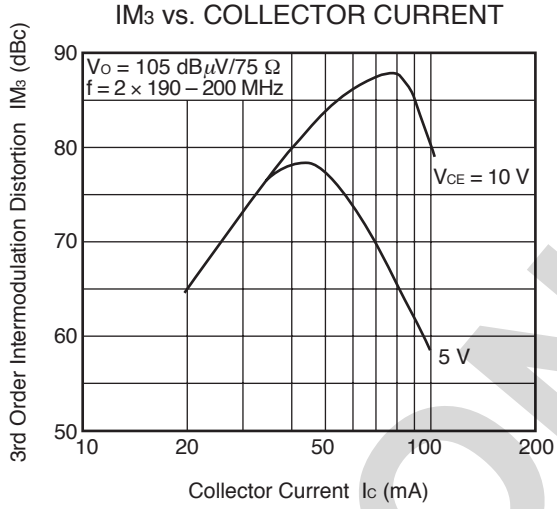
NOISE FIGURE vs.
COLLECTOR CURRENT



IM2 vs. COLLECTOR CURRENT



IM3 vs. COLLECTOR CURRENT



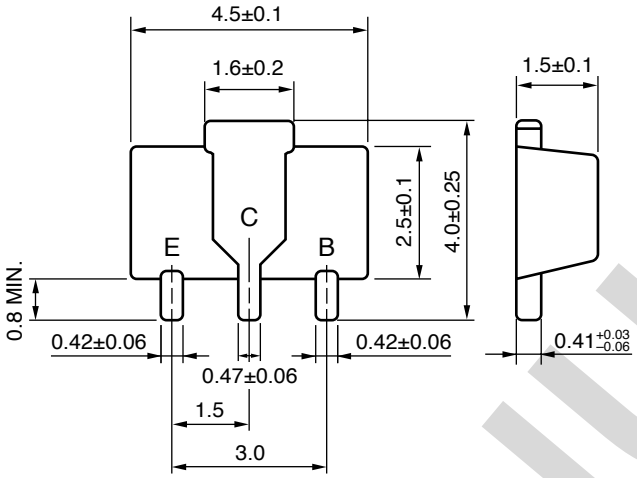
Remark The graphs indicate nominal characteristics.

S-PARAMETERS

- S-parameters and noise parameters are provided on our Web site in a format (S2P) that enables the direct import of the parameters to microwave circuit simulators without the need for keyboard inputs.
- Click here to download S-parameters.
- [RF and Microwave] ® [Device Parameters]
- URL http://www.necel.com/microwave/en/

★ **PACKAGE DIMENSIONS**

3-PIN POWER MINIMOLD (UNIT: mm)



PIN CONNECTIONS

E : Emitter
C : Collector (Fin)
B : Base

(IEC : SOT-89)

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